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Lead-free Green

**DMT35M4LFVW**

**30V N-CHANNEL ENHANCEMENT MODE MOSFET**
**PowerDI3333-8**

## Product Summary

| $BV_{DSS}$ | $R_{DS(ON)}$ Max | $I_D$ Max $T_C$ = +25°C |
|---|---|---|
| 30V | 6mΩ @ $V_{GS}$ = 10V | 60A |
| | 9mΩ @ $V_{GS}$ = 4.5V | 48A |

## Features

- Low $R_{DS(ON)}$ – Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% Unclamped Inductive Switching (UIS) Test in Production – Ensures More Reliable and Robust End Application
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

## Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

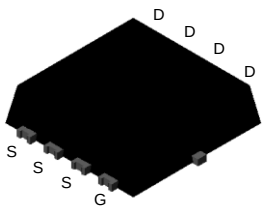
## Applications

- Power Management Functions
- Analog Switch

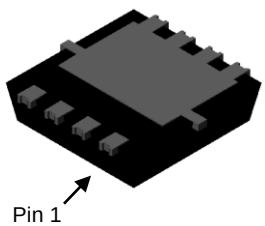
## Mechanical Data

- Case: PowerDI®3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish — Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.03 grams (Approximate)

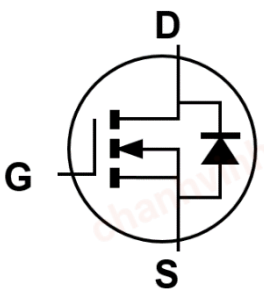
PowerDI3333-8 (SWP) (Type UX)




Top View




Bottom View




Equivalent Circuit

## Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---|---|---|
| DMT35M4LFVW-7 | PowerDI3333-8 (SWP) (Type UX) | 2,000/Tape & Reel |
| DMT35M4LFVW-13 | PowerDI3333-8 (SWP) (Type UX) | 3,000/Tape & Reel |

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## Marking Information




SH4 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 20 = 2020)
WW = Week Code (01 to 53)

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## Maximum Ratings (@$T_A$ = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|---|---|---|---|---|
| Drain-Source Voltage | | | $V_{DSS}$ | 30 | V |
| Gate-Source Voltage | | | $V_{GSS}$ | ±20 | V |
| Continuous Drain Current, $V_{GS}$ = 10V (Note 6) | Steady State | $T_A$ = +25°C<br>$T_A$ = +70°C | $I_D$ | 16<br>13 | A |
| | Steady State | $T_C$ = +25°C<br>$T_C$ = +70°C | $I_D$ | 60<br>48 | A |
| Maximum Body Diode Forward Current (Note 6) | | | $I_S$ | 2.3 | A |
| Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%) | | | $I_{DM}$ | 110 | A |
| Pulsed Drain Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%) | | | $I_{SM}$ | 110 | A |
| Avalanche Current (L = 0.1mH) (Note 8) | | | $I_{AS}$ | 22 | A |
| Avalanche Energy (L = 0.1mH) (Note 8) | | | $E_{AS}$ | 25 | mJ |

## Thermal Characteristics (@$T_A$ = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|---|---|---|---|---|
| Total Power Dissipation (Note 5) | | $P_D$ | 1.5 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | $R_{\theta JA}$ | 83.3 | °C/W |
| Total Power Dissipation (Note 6) | | $P_D$ | 2.2 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | $R_{\theta JA}$ | 55 | °C/W |
| Thermal Resistance, Junction to Case (Note 7) | | $R_{\theta JC}$ | 3.9 | |
| Operating and Storage Temperature Range | | $T_J$, $T_{STG}$ | -55 to +150 | °C |

## Electrical Characteristics (@$T_A$ = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---|---|---|---|---|---|
| **OFF CHARACTERISTICS** (Note 9) | | | | | | |
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | 30 | — | — | V | $V_{GS}$ = 0V, $I_D$ = 250µA |
| Zero Gate Voltage Drain Current $T_J$ = +25°C | $I_{DSS}$ | — | — | 1 | µA | $V_{DS}$ = 24V, $V_{GS}$ = 0V |
| Gate-Source Leakage | $I_{GSS}$ | — | — | ±100 | nA | $V_{GS}$ = ±20V, $V_{DS}$ = 0V |
| **ON CHARACTERISTICS** (Note 9) | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | 1.15 | — | 2.5 | V | $V_{DS}$ = $V_{GS}$, $I_D$ = 250µA |
| Static Drain-Source On-Resistance | $R_{DS(ON)}$ | — | 4.6 | 6 | mΩ | $V_{GS}$ = 10V, $I_D$ = 20A |
| | | | 6.5 | 9 | | $V_{GS}$ = 4.5V, $I_D$ = 15A |
| Diode Forward Voltage | $V_{SD}$ | — | 0.7 | 1 | V | $V_{GS}$ = 0V, $I_S$ = 1A |
| **DYNAMIC CHARACTERISTICS** (Note 10) | | | | | | |
| Input Capacitance | $C_{iss}$ | — | 982 | — | pF | $V_{DS}$ = 15V, $V_{GS}$ = 0V, f = 1.0MHz |
| Output Capacitance | $C_{oss}$ | — | 903 | — | | |
| Reverse Transfer Capacitance | $C_{rss}$ | — | 27 | — | | |
| Gate Resistance | $R_g$ | — | 2.2 | — | Ω | $V_{DS}$ = 0V, $V_{GS}$ = 0V, f = 1.0MHz |
| Total Gate Charge ($V_{GS}$ = 4.5V) | $Q_g$ | — | 7.9 | — | nC | $V_{DD}$ = 15V, $I_D$ = 9A |
| Total Gate Charge ($V_{GS}$ = 10V) | $Q_g$ | — | 16.1 | — | | |
| Gate-Source Charge | $Q_{gs}$ | — | 3.6 | — | | |
| Gate-Drain Charge | $Q_{gd}$ | — | 1.2 | — | | |
| Turn-On Delay Time | $t_{D(ON)}$ | — | 8.1 | — | ns | $V_{DD}$ = 15V, $V_{GS}$ = 10V, $R_g$ = 3Ω, $I_D$ = 9A |
| Turn-On Rise Time | $t_R$ | — | 2.2 | — | | |
| Turn-Off Delay Time | $t_{D(OFF)}$ | — | 16.8 | — | | |
| Turn-Off Fall Time | $t_F$ | — | 5.7 | — | | |

Notes:
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. $I_{AS}$ and $E_{AS}$ ratings are based on low frequency and duty cycles to keep $T_J$ = +25°C.
9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.


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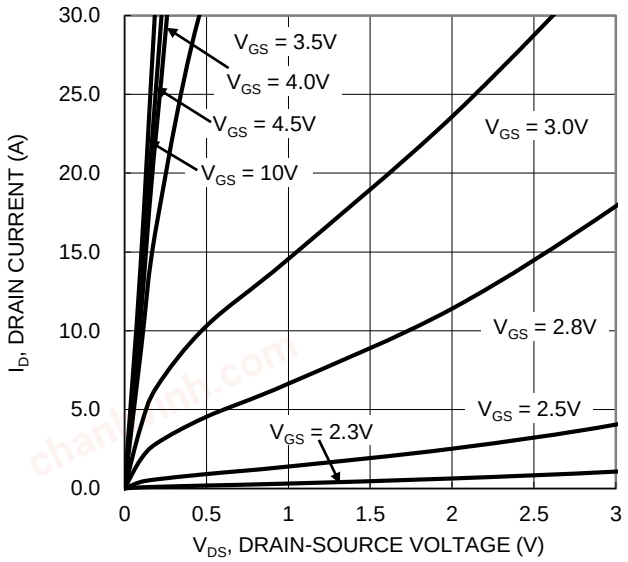



Figure 1. Typical Output Characteristic

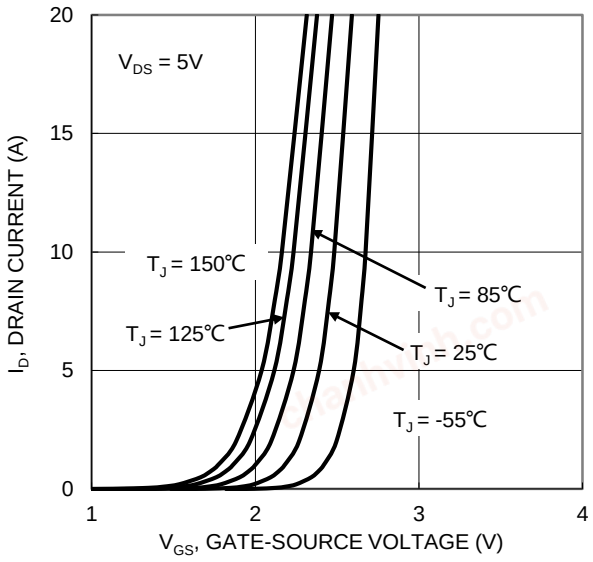



Figure 2. Typical Transfer Characteristic

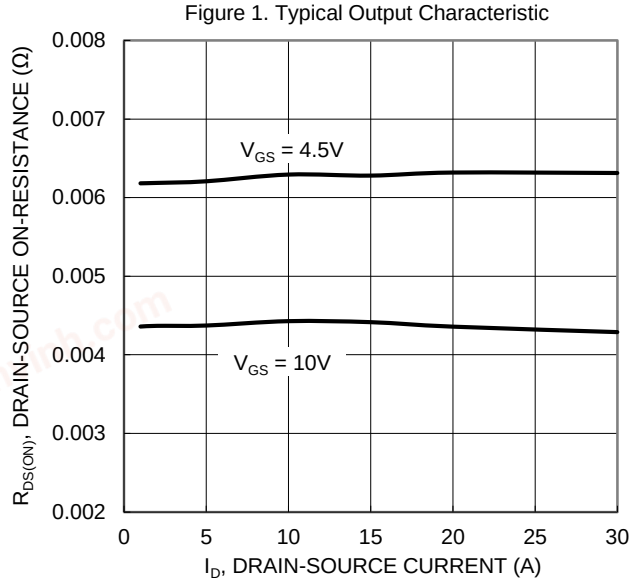



Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

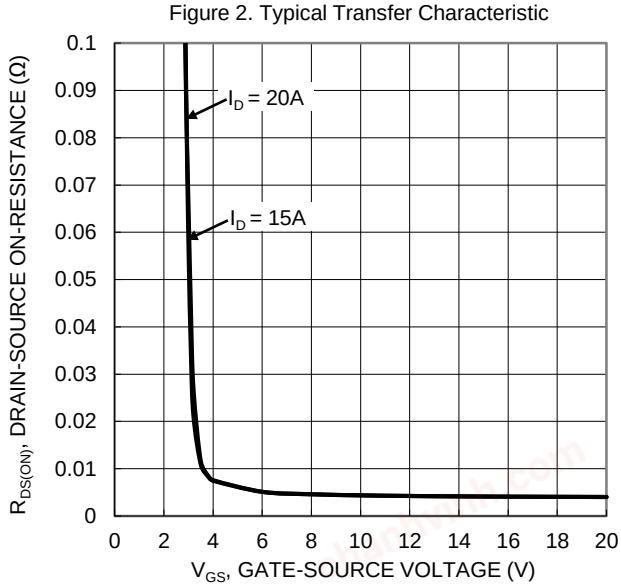



Figure 4. Typical Transfer Characteristic

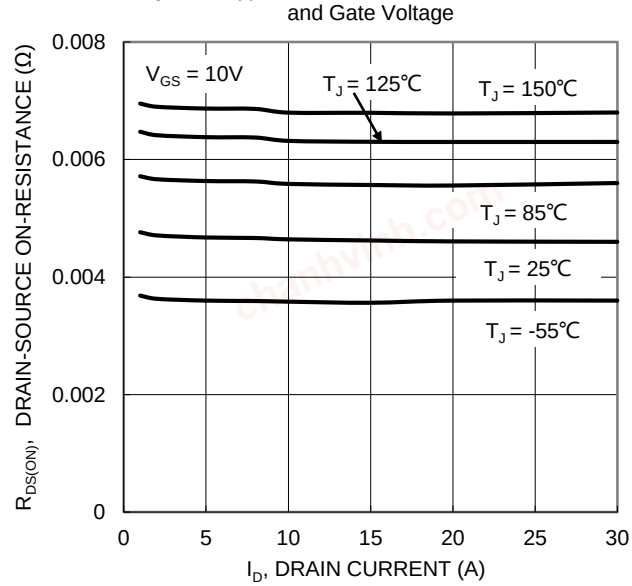



Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

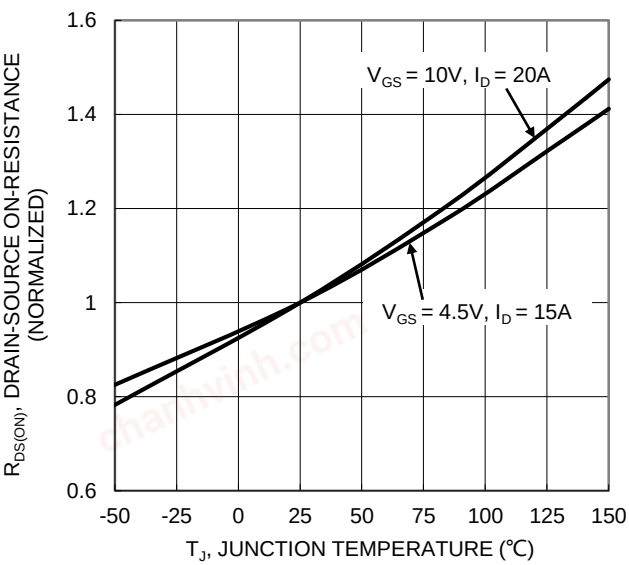



Figure 6. On-Resistance Variation with Junction Temperature


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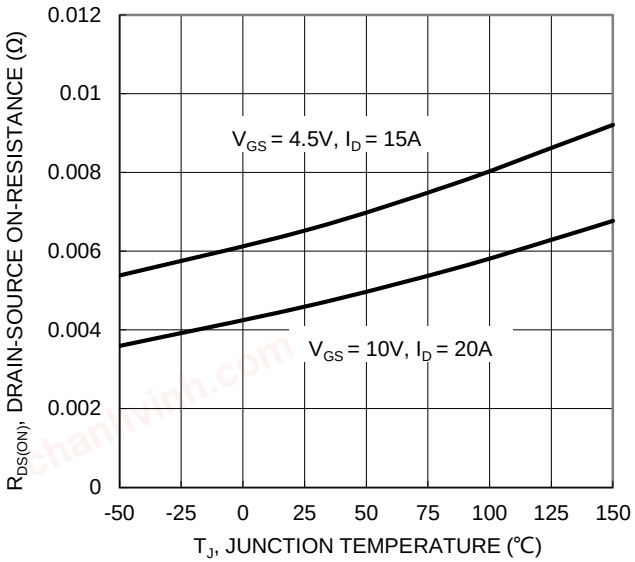



Figure 7. On-Resistance Variation with Junction Temperature

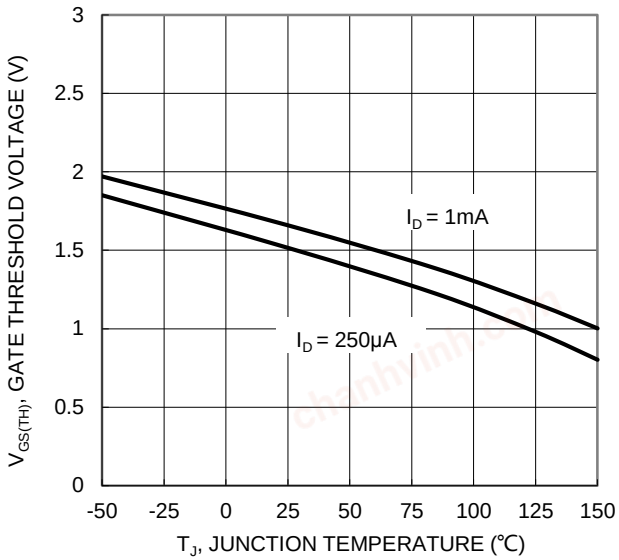



Figure 8. Gate Threshold Variation vs. Junction Temperature

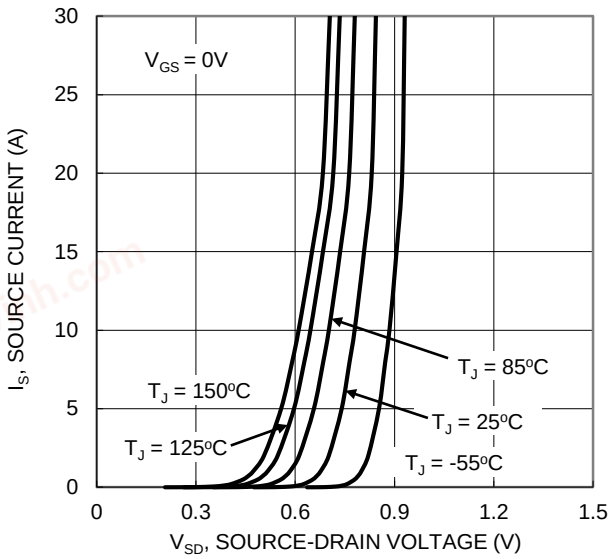



Figure 9. Diode Forward Voltage vs. Current

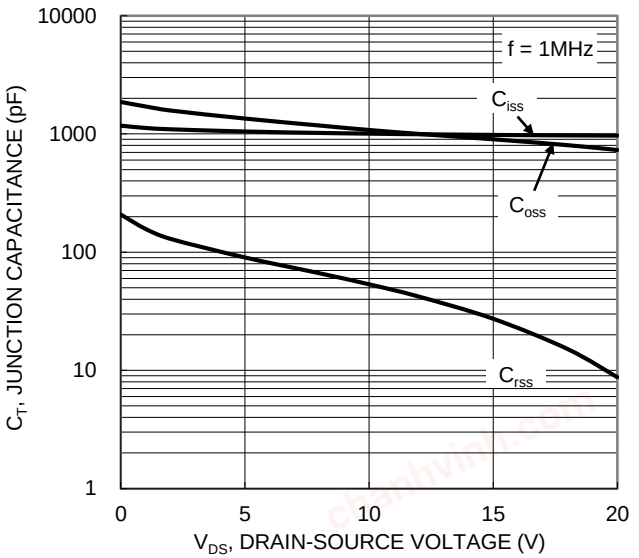



Figure 10. Typical Junction Capacitance

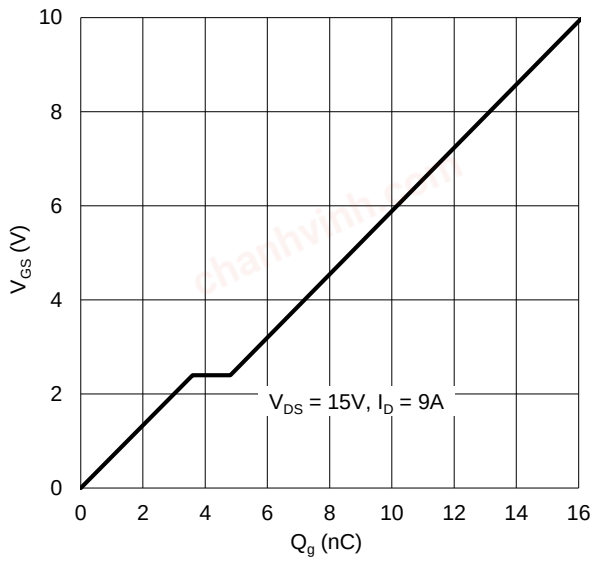



Figure 11. Gate Charge

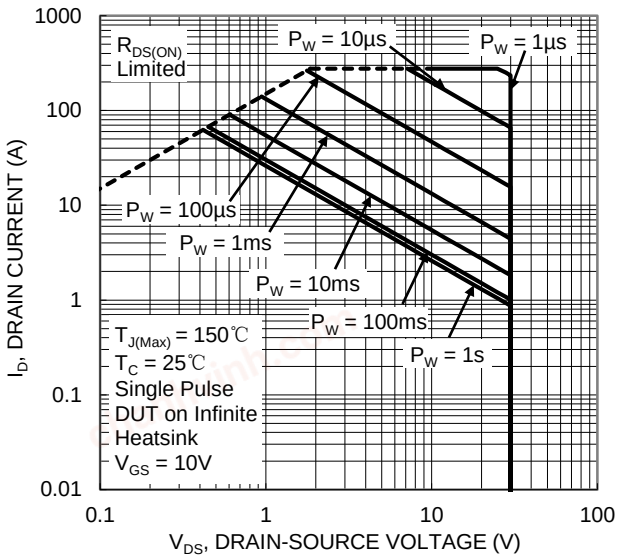



Figure 12. SOA, Safe Operation Area


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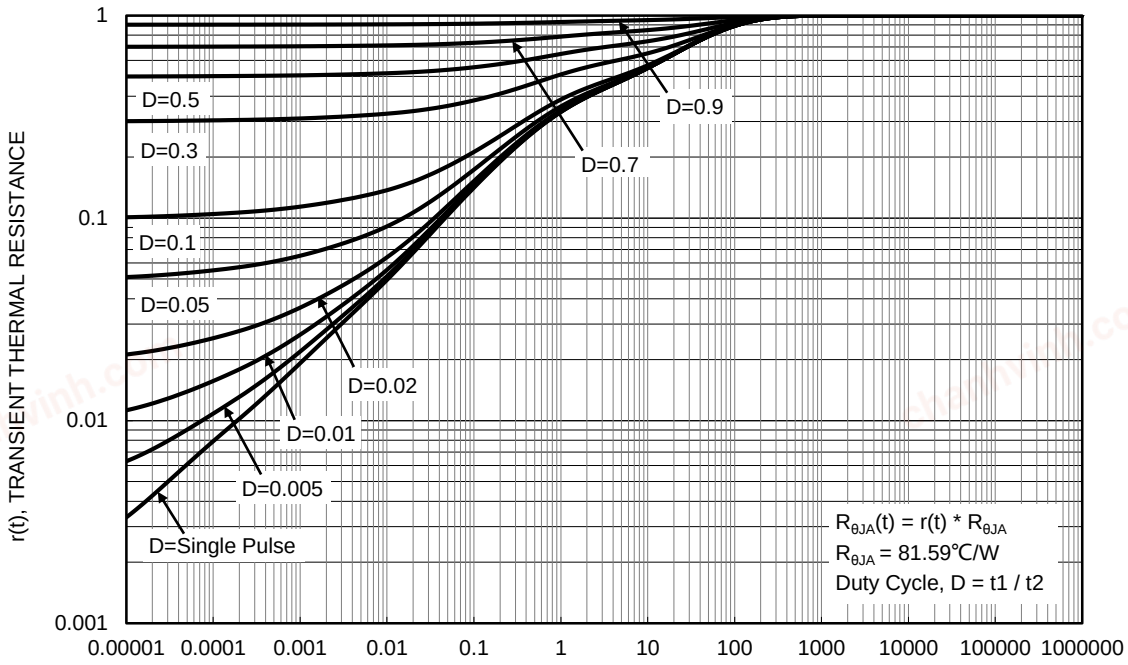



Figure 13. Transient Thermal Resistance


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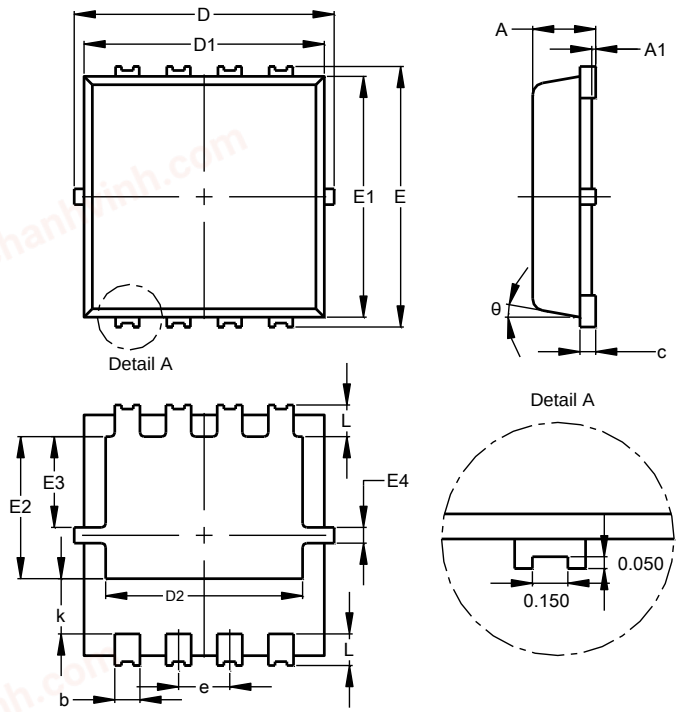
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## Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

**PowerDI3333-8 (SWP) (Type UX)**

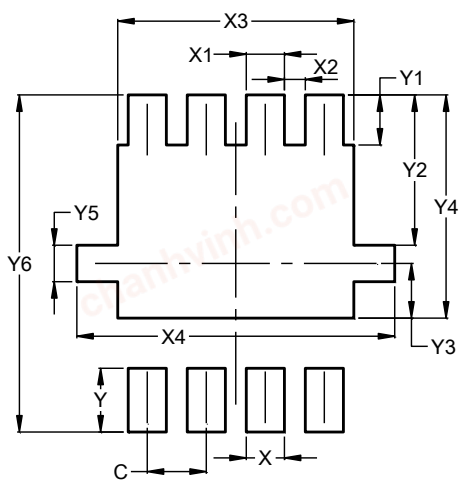



| PowerDI3333-8 (SWP) (Type UX) | | | |
|---|---|---|---|
| **Dim** | **Min** | **Max** | **Typ** |
| **A** | 0.75 | 0.85 | 0.80 |
| **A1** | 0.00 | 0.05 | -- |
| **b** | 0.25 | 0.40 | 0.32 |
| **c** | 0.10 | 0.25 | 0.15 |
| **D** | 3.20 | 3.40 | 3.30 |
| **D1** | 2.95 | 3.15 | 3.05 |
| **D2** | 2.30 | 2.70 | 2.50 |
| **E** | 3.20 | 3.40 | 3.30 |
| **E1** | 2.95 | 3.15 | 3.05 |
| **E2** | 1.60 | 2.00 | 1.80 |
| **E3** | 0.95 | 1.35 | 1.15 |
| **E4** | 0.10 | 0.30 | 0.20 |
| **e** | – | – | 0.65 |
| **k** | 0.50 | 0.90 | 0.70 |
| **L** | 0.30 | 0.50 | 0.40 |
| **θ** | 0° | 12° | 10° |
| **All Dimensions in mm** | | | |

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

**PowerDI3333-8 (SWP) (Type UX)**




| Dimensions | Value (in mm) |
|---|---|
| **C** | 0.650 |
| **X** | 0.420 |
| **X1** | 0.420 |
| **X2** | 0.230 |
| **X3** | 2.600 |
| **X4** | 3.500 |
| **Y** | 0.700 |
| **Y1** | 0.550 |
| **Y2** | 1.650 |
| **Y3** | 0.600 |
| **Y4** | 2.450 |
| **Y5** | 0.400 |
| **Y6** | 3.700 |


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